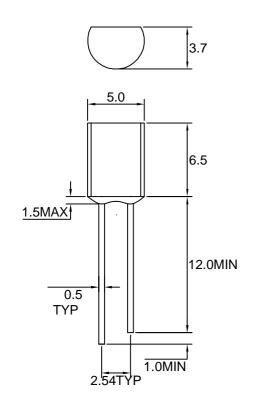


PHOTO DIODE SILICON PIN LED LAMPS

LPD4380

SERIES

Package Dimension



NOTE:1.All dimension are In millimeters tolerance Is ±0.25 unless otherwise noted 2.Specifications are subject to change without notice

Description

The LPD4380 series are silicon planar P/N photodiodes incorporated in plastic package that simultaneously serve as filter and are also Transparent for infrared emission their terminals are soldering tabs arranged in 2.54mm center to center spacing due to their design the diodes can vertically be assembled on pc boards arrays can be realized by multiple arrangement versatile photodetectors are suitable for diodes as well as voltaic cell operation the signal noise ratio is particularly favorable even at low illuminance the P/N photodiode are outstanding for low junction capacitance high cut-off frequency and fast switching times.

They are particularly suitable for IR sound transmission and remote control the cathode of LPD4380 photodiode is marked by a stamping on the package edge

MAXIMUN RATINGS (TA=25)

Characteristic	Symbol	Rating	∪nit
Reversr Break Down Voltage	VBR	30	V
Power Dissipation	PD	150	mW
Operating Temperature	Topr	-30 - +60	
Storage Temperature	Tstg	-40 - +60	

ELECTRICAL CHARACTERISTICS AT (TA=)

Symbol	Test Condition	Min	Тур	Max	Unit
lo	V _R =10V Ee=0mW/cm ²	-	1.0	30	nA
Isc	V _R =5V P=940nm Ee=0.5mW/cm ²	1.5	2.0	-	uA
Voc	P=940nm Ee=0.5mW/cm²	_	350	-	mV
Ст	VR=3V f=1MHZ Ee=0mW/cm²	-	20	-	pF
smax		-	940	-	nm
tr,tf	VR=10V RL=1K	-	50	-	ns
	ID ISC Voc CT smax	ID	ID	ID	ID

DOC.NO: QW0905-LPD4380

REV:D

Date: 18 - Aug. - 2005